



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
-30V	5Ω @ Vgs = -4.5V	-0.2A
	6Ω @ Vgs = -2.5V	-0.18A
	7Ω @ Vgs = -1.8V	-0.17A
	10Ω @ Vgs = -1.5V	-0.14A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- Analog Switch

30V P-CHANNEL ENHANCEMENT MODE MOSFET

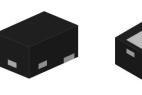
Features and Benefits

- Low Package Profile
- 0.6mm × 0.4mm Package Footprint
- Low On-Resistance
- Very Low Gate Threshold Voltage, -1.0V Max
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: X2-DFN0604-3
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu over Copper Lead-Frame; Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.001 grams (Approximate)

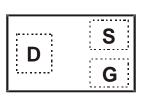




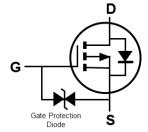
X2-DFN0604-3

Top View

Bottom View



Top View Package Pin Configuration



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP32D9UFO-7B	X2-DFN0604-3	10k /Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



BE = Product Type Marking Code Bar Denotes Gate and Source Side

Top View



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V _{DSS}	-30	V
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Drain Current (Note 5) V_{GS} = -4.5V	Steady	T _A = +25°C	ID	-0.2	A
	State	T _A = +70°C		-0.16	
Maximum Continuous Body Diode Forward Current (Note 6)			Is	-0.8	A
Pulsed Drain Current (Note 6)			I _{DM}	-0.8	A

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	Steady State	PD	320	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	386	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

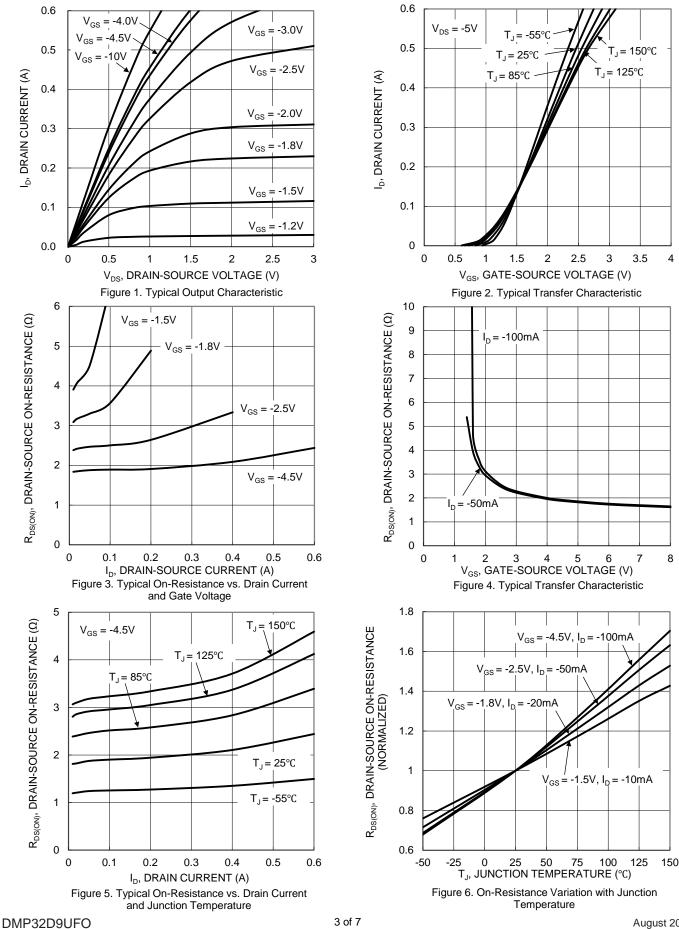
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-100	nA	$V_{DS} = -24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-0.4	-	-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
		_	1.9	5	Ω	$V_{GS} = -4.5V, I_D = -100mA$	
Static Drain-Source On-Resistance	Desser	_	2.5	6		$V_{GS} = -2.5V, I_D = -50mA$	
	R _{DS(ON)}	_	3.2	7		$V_{GS} = -1.8V, I_D = -20mA$	
		_	3.7	10		$V_{GS} = -1.5V, I_D = -10mA$	
Diode Forward Voltage	V _{SD}	_	-0.6	-1.0	V	$V_{GS} = 0V, I_{S} = -10mA$	
DYNAMIC CHARACTERISTICS (Note 8)				•		·	
Input Capacitance	Ciss	—	21.8	_	pF		
Output Capacitance	C _{oss}	—	2.82	_	pF	V _{DS} = -15V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	1.66		pF		
Total Gate Charge	Qg	_	0.35		nC		
Gate-Source Charge	Q _{gs}	_	0.05		nC	V _{GS} = -4.5V, V _{DS} = -15V, I _D = -200mA	
Gate-Drain Charge	Q _{gd}	—	0.10	_	nC	-10 = -200MA	
Turn-On Delay Time	t _{D(ON)}	—	3.5		ns		
Turn-On Rise Time	t _R	—	5.2	_	ns	V _{DD} = -15V, V _{GS} = -4.5V,	
Turn-Off Delay Time	t _{D(OFF)}	—	18.8	_	ns	$R_g = 2\Omega$, $I_D = -200 \text{mA}$	
Turn-Off Fall Time	t _F	_	8.7	—	ns	1	

Notes:

5. Device mounted on FR-4 PCB, with minimum recommended pad layout.
6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.



DMP32D9UFO

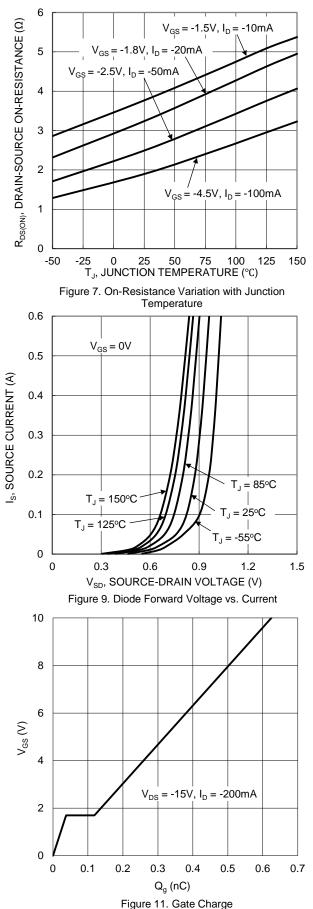


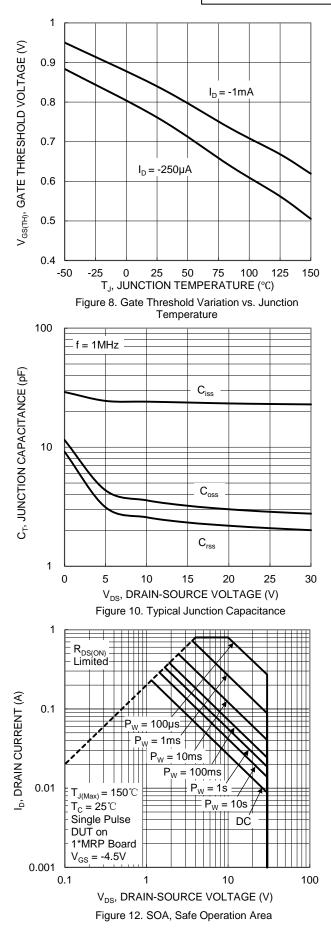
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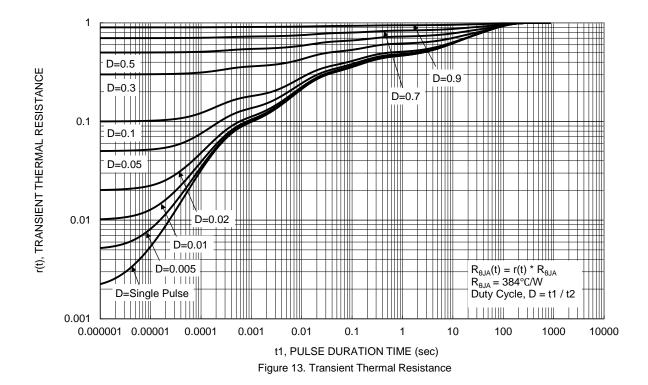






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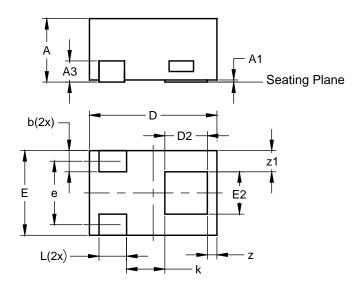






Package Outline Dimensions

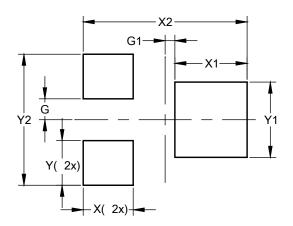
Please see http://www.diodes.com/package-outlines.html for the latest version.



X2-DFN0604-3					
Dim	Min	Max	Тур		
Α		0.40	0.36		
A1	0.00	0.03	0.02		
A3			0.10		
b	0.07	0.15	0.10		
D	0.55	0.65	0.60		
D2	0.15	0.25	0.20		
E	0.35	0.45	0.40		
E2	0.15	0.25	0.20		
е			0.30		
k	0.15				
L	0.10	0.18	0.13		
z			0.045		
z1			0.10		
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
G	0.075
G1	0.035
X	0.180
X1	0.260
X2	0.590
Y	0.160
Y1	0.270
Y2	0.470



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